

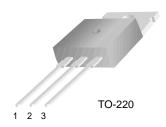
## FFP04U40DN

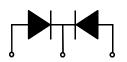
### **Features**

- · Ultrafast with soft recovery
- · Low forward voltage

## **Applications**

- Power switching circuits
- Output rectifiers
- Freewheeling diodes
- Switching mode power supply





1. Anode 2. Cathode 3. Anode

## **ULTRA FAST RECOVERY POWER RECTIFIER**

### Absolute Maximum Ratings (per diode) T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	400	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 100°C	4	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	40	Α
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and Storage Temperature	- 65 to +150	°C

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
R <sub>e.IC</sub>	Maximum Thermal Resistance, Junction to Case	10	°C/W

## Electrical Characteristics (per diode) T<sub>C</sub>=25 °C unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V <sub>FM</sub> *	Maximum Instantaneous Forward Voltage					V
	I <sub>F</sub> = 4A	T <sub>C</sub> = 25 °C	-	-	1.4	
	I <sub>F</sub> = 4A	$T_C = 25 ^{\circ}C$ $T_C = 100 ^{\circ}C$	-	-	1.3	
I <sub>RM</sub> *	Maximum Instantaneous Reverse Current					μΑ
	@ rated V <sub>R</sub>	$T_C = 25  ^{\circ}C$	-	-	10	
		$T_C = 25$ °C $T_C = 100$ °C	-	-	100	
t <sub>rr</sub>	Maximum Reverse Recovery Time		-	-	45	ns
I <sub>rr</sub>	Maximum Reverse Recovery Current		-	-	3.0	Α
Q <sub>rr</sub>	Maximum Reverse Recovery Charge		-	-	68	nC
••	$(I_F = 4A, di/dt = 200A/\mu s)$					
W <sub>AVL</sub>	Avalanche Energy		1.0	-	-	mJ

<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

# **Typical Characteristics**

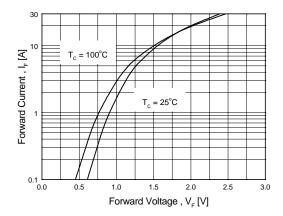


Figure 1. Typical Forward Voltage Drop vs. Forward Current

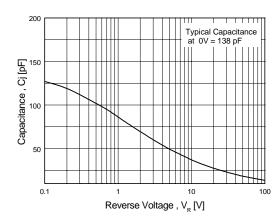


Figure 3. Typical Junction Capacitance

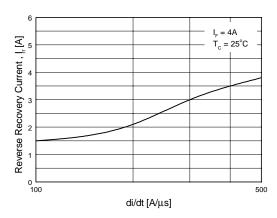


Figure 5. Typical Reverse Recovery Current vs. di/dt

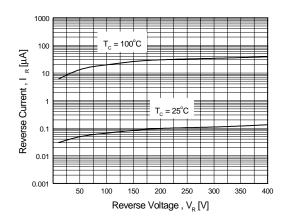


Figure 2. Typical Reverse Current vs. Reverse Voltage

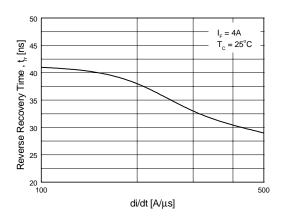


Figure 4. Typical Reverse Recovery Time vs. di/dt

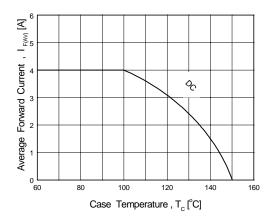
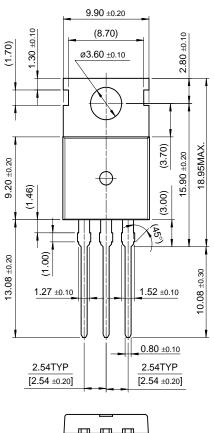
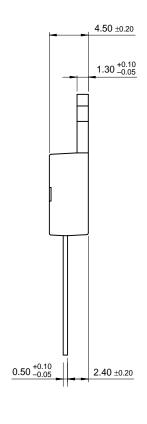


Figure 6. Forward Current Derating Curve

# **Package Dimensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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